

C3D25170H-Silicon Carbide Schottky Diode

Z-RECTM RECTIFIER

 $V_{RRM} = 1700 \text{ V}$ $I_{F;} T_{c} < 135^{\circ} C = 26.3 \text{ A}$ $Q_{c} = 230 \text{ nC}$

Features

- 1700-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Halogen-Free; RoHS Complaint

Package







Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway



Part Number	Package	Marking	
C3D25170H	TO-247-2	C3D25170	

Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions	Note
V _{RRM}	Repetitive Peak Reverse Voltage	1700	V		
V _{RSM}	Surge Peak Reverse Voltage	1700	V	v	
V _{DC}	DC Blocking Voltage	1700	V		
I _F	Continuous Forward Current	26.3	А	T _c <135°C	
I _{FRM}	Repetitive Peak Forward Surge Current	99 57	А	T_c =25°C, t_p =10 ms, Half Sine Wave, D=1 T_c =110°C, t_p =10 ms, Half Sine Wave, D=1	
\mathbf{I}_{FSM}	Non-Repetitive Peak Forward Surge Current	117 88	А	T_c =25°C, t_p =10ms, Half Sine Wave, D=1 T_c =110°C, t_p =10 ms, Half Sine Wave, D=1	
P _{tot}	Power Dissipation	377 163	W	T _c =25°C T _c =110°C	
T _c	Maximum Case Temperature	135	°C		
T,	Operating Junction Range	-55 to +175	°C	С	
T _{stg}	Storage Temperature Range	-55 to +135	°C		
	TO-247 Mounting Torque	1 8.8	Nm lbf-in	M3 Screw 6-32 Screw	



Electrical Characteristics

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V _F	Forward Voltage	1.8 3.2	2.5 4	V	$I_F = 25 \text{ A } T_J = 25^{\circ}\text{C}$ $I_F = 25 \text{ A } T_J = 175^{\circ}\text{C}$	
I _R	Reverse Current	20 100	100 400	μΑ	V _R = 1700 V T _J =25°C V _R = 1700 V T _J =175°C	
Q_{c}	Total Capacitive Charge	230		nC	$V_R = 1700 \text{ V, } I_F = 25 \text{ A} $ $di/dt = 200 \text{ A/}\mu\text{s} $ $T_J = 25^{\circ}\text{C}$	
С	Total Capacitance	2079 187.5 97		pF	$V_R = 0 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$ $V_R = 200 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$ $V_R = 800 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$	

Note

Thermal Characteristics

Symbol	Parameter	Тур.	Unit
$R_{\theta JC}$	Thermal Resistance from Junction to Case	0.4	°C/W

Typical Performance

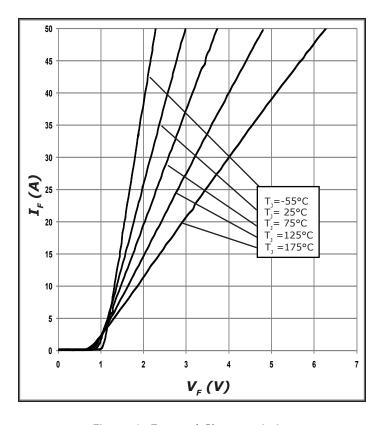


Figure 1. Forward Characteristics

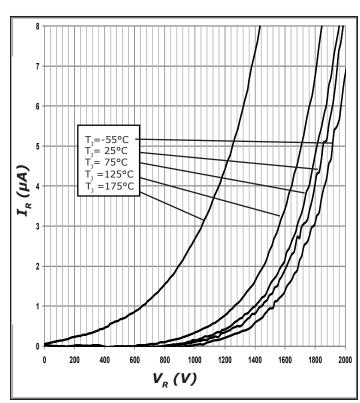
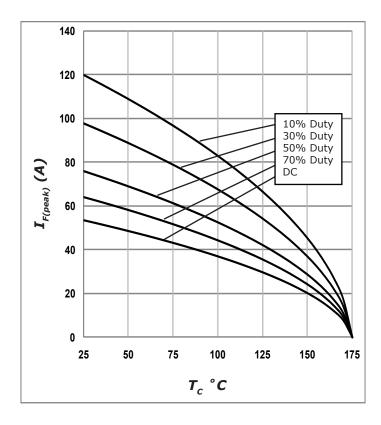


Figure 2. Reverse Characteristics

^{1.} This is a majority carrier diode, so there is no reverse recovery charge.





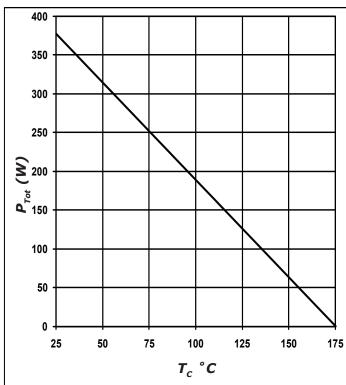


Figure 3. Current Derating

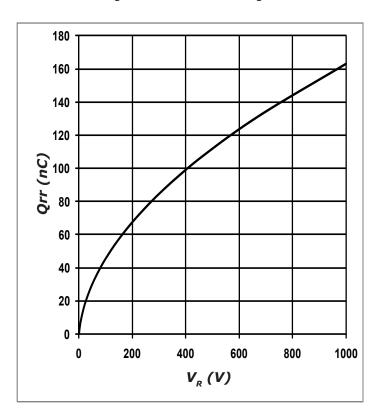


Figure 5. Recovery Charge vs. Reverse Voltage

Figure 4. Power Derating

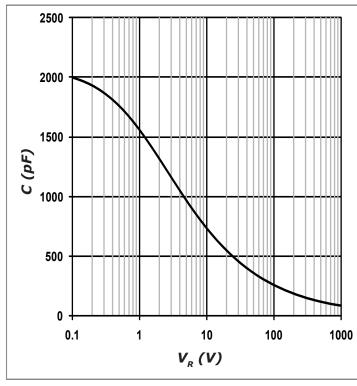


Figure 6. Capacitance vs. Reverse Voltage



Typical Performance

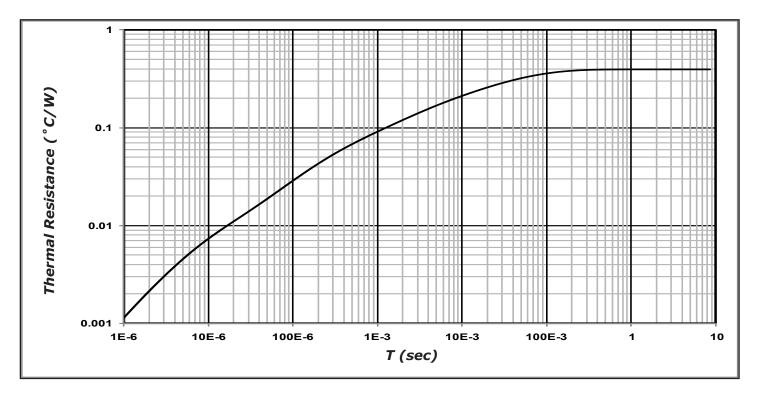


Figure 7. Transient Thermal Impedance

Diode Model

$$\begin{array}{c|c} - & & \\ \hline V_T & R_T \end{array}$$

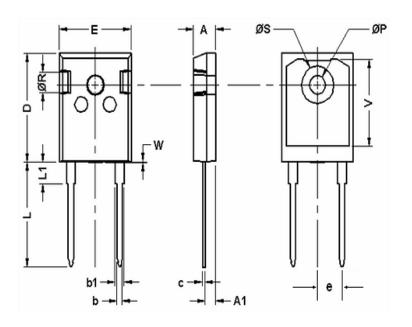
$$Vf_{T} = V_{T} + If^{*}R_{T}$$

$$V_{T} = 0.99 + (T_{J}^{*} - 1.50^{*}10^{-3})$$

$$R_{T} = 0.03 + (T_{J}^{*} 0.5^{*}10^{-3})$$

Note: Tj = Diode Junction Temperature in Degrees Celsius





POC	Inc	hes	Millimeters		
POS	Min	Max	Min	Max	
Α	0.185	0.209	4.70	5.31	
A1	0.087	0.102	2.21	2.59	
b	0.040	0.055	1.02	1.40	
b1	0.065	0.088	1.65	2.23	
С	0.016	0.031	0.41	0.79	
D	0.819	0.845	20.80	21.46	
Е	0.61	0.640	15.49	16.26	
е	0.215	0.215	5.46	5.46	
L	0.78	0.80	19.81	20.32	
L1	0.164	0.176	4.17	4.47	
øΡ	0.140	0.144	3.56	3.66	
Q	0.212	0.244	5.38	6.20	
øR	0.135	0.157	3.43	3.99	
øS	0.278	0.288	7.06	7.32	
V	0.652	0.662	16.56	16.81	
W	0.000	0.006	0.00	0.15	



"The levels of environmentally sensitive, persistent biologically toxic (PBT), persistent organic pollutants (POP), or otherwise restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2002/95/EC on the restriction of the use of certain hazardous substances in electrical and electronic equipment (RoHS), as amended through April 21, 2006.

This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, air traffic control systems, or weapons systems.

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